

STUDY OF DRIFT-FIELD SOLAR CELLS DAMAGED BY LOW-ENERGY PROTONS

Contract NAS 5-9627

Report Covering Period of October 15 to November 19, 1965

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1. OBJECTIVE

The objective is to conduct an irradiation study of drift-field solar cells (supplied by NASA) with low-energy protons. The experimental data are to consist of I-V curves and spectral response curves. The data are to be analyzed with the aid of a solar-cell model.

2. WORK SUMMARY

The irradiation was performed and reported in the previous monthly report (Ref. 1). The solar cells were mounted on Disks 13, 15, 16, 14,10, and 17 and irradiated at 2.53 Mev, 1.04 Mev, 1.04, 470 kev, 221 kev, and 221 kev, respectively. A typical I-V curve or spectral response curve is coded by three numbers, the first giving the disk number, the second, the irradiation run number, and the third, the cell position number. For an example, the code number, 13-4-5, refers to Disk 13, Run 4, and Cell-Position 5. Run 0 is a pre-irradiation run, Runs 1-6 are runs in which the cells were all irradiated to a particular proton fluence, and Runs 7 and 8 are runs to check on annealing.

Table 1 of the previous monthly report correlates cell-position numbers for each disk with the cell designation supplied by the manufacturer. Table 2 of that report gives the proton fluences corresponding to the code numbers. The values of these fluences are presently being re-examined as a result of comparing the damage obtained for uniform cells irradiated in the experiment of September 27-30, 1965 with the damage obtained for uniform cells in earlier experiments (Ref. 2-4). The experimental work this month was the measurement of the I-V curves of all irradiated cells to check on annealing effects (Run 8), the measurement of the spectral responses of three unirradiated control cells used to check stability of the O.C.L.I. sun simulator, the measurement of the spectral response of the cells on Disk 14, to check on annealing effects (Run 8), and the measurement of the effect of cleaning the filters in the filter-wheel spectrometer.

The computer program used to calculate the spectral response of a solar cell was modified to include two auxiliary computer programs. These programs calculate the number of layers and the width of each layer in the base of the n-layer solar cell model and the average values of the input parameters for each layer in such a way that the variations of the parameters over each layer are less than 10%. The first auxiliary program, called the "E" program, is used for uniform solar cells damaged by protons of energy, E. The second auxiliary program, called the "N" program, is used for unirradiated drift-field cells having a range of impurity atom densities, $N_1 \leq N \leq N_2$. A third auxiliary program, called the "N+E" program, is being developed to combine the "E" and "N" auxiliary programs for use with irradiated drift-field solar cells.

3. CONFORMANCE OR NON-CONFORMANCE WITH THE WORK SCHEDULE

The analysis of the data is proceeding satisfactorily and is considered to be on schedule.

4. ANALYSIS OF THE WORK

All the I-V curves were fitted to a modified diode equation to yield two parameters, $R_{\rm s}$, the series resistance, and N, the coefficient of the kT term. These results are expected to be meaningful for the uniform cells but are not interpretable for the drift-field cells because of the negative values of $R_{\rm s}$ which frequently appear. However, because the fits are quite close, the results of the curve fitting serve to check irregularities in the data and to present the results in a compact form. Tables 1-12 give the results of the curve fitting. The "cell" column gives the code numbers of the cells.

The code numbers for each cell are grouped and the grouping identified by the manufacturer's designation for that cell. During the I-V measurements with the O.C.L.I. simulator the cells were cooled with an air blower and held to a room temperature estimated to be $298^{\circ}\mathrm{K}$. The fourth column gives the short-circuit current, I_{SC} . The fifth column gives the open-circuit voltage, V_{OC} .

The fifth and sixth columns give R_s and N. The seventh, eighth, and ninth columns give the values of the maximum power and the coordinates of the maximum power.

For Disk 13 the drift-field cells are E-33-1A, E-33-2C, H-105, 72, and 82 while the uniform cells are located in cell positions 7, 8, and 9. The high value of N belonging to code number 13-6-9 is not a fault of the analysis but is thought to be caused by an electrical switching error during the measurements. Note that R_3 is positive for the three uniform cells except for the one coded 13-6-9.

For Disk 15, the drift-field cells are E-34-2D, E-35-4A, H-98, H-106, 76, and 85 while the uniform cells are located in the positions 7, 8, and 9. Note that $R_{\rm g}$ is positive for the three uniform cells.

For Disk 16, the drift-field cells are TI-3-2 (25 μ) and TI-4-2 (12 μ) while the uniform cells are located in the positions 4 and 5. Note that R is positive for the two uniform cells.

For Disk 14, the drift-field cells are H-61, 56, TI-3-3(25), TI-4-1(12), and E-54-8a while the uniform cells are located in the positions 3 and 4. Note that $R_{\rm S}$ is positive for the cell, H-10 Ω cm, in position 3 but is negative for the cell, H-1 Ω cm, in position 4.

For Disk 10, the drift-field cells are E-33-3A, E-33-2A, H-68, H-75, 62 and 64 while the uniform cells are at positions 7 and 9. Note that $R_{\rm S}$ is partly positive and partly negative for the uniform cells in positions 7 and 9.

For Disk 17, the drift-field cells are TI-3-1(25 μ), TI-4-3(12 μ) and E-55-1c while the uniform cells are at positions 5 and 6. For the most part, the values of R_S for the uniform cells are positive.

No explanation is offered at present for the negative values of $R_{_{\rm S}}$ which occasionally are shown for the uniform cells.

The drift-field solar cell, No. 82 (Texas Instruments, Inc.), was chosen as a test case in comparing a measured spectral response with a spectral response calculated from the n-layer solar cell model (Ref. 5). This particular choice was made because information concerning this cell is given in Table VII of the Technical Summary Report (Ref. 6) published by the Texas Instruments, Inc.

The parameter on which several other parameters depend in calculating the spectral response of a drift-field cell from the solar cell model is the impurity (acceptor) atom density, N, which is a function of the distance, x, below the junction. Figure 1 depicts the different layers in the construction of a drift-field solar cell. Initially, the epitaxial and substrate layers have the uniform impurity atom densities, N_1 and N_2 . Diffusion causes a new distribution of impurity atom densities to be produced when the two layers are raised to an elevated temperature for a time, t. After this process is completed an N/P junction is produced in the epitaxial layer at a distance, d_0 , below its surface. The new distribution of impurity atom densities is assumed to have the form

$$N(x) = a + b \operatorname{erf}(\frac{x-c}{d}) \qquad \dots (1)$$

where

$$a = \frac{N_1 + N_2}{2}$$
, ... (2)

$$b = \frac{N_2 - N_1}{2} , \qquad ... (3)$$

$$c = w - d_{O} , \qquad ... (4)$$

and

$$d = {}^{1}4D_{B}t \qquad ... (5)$$

In the last formula the diffusion coefficient, $D_{\rm B}$, is evaluated for boron in silicon for the elevated temperature at which the diffusion process takes place. Numerical values which are pertinent to drift-field cell, No.82, are

 $N_1 = 10^{15}$ atoms/cm³, corresponding to a resistivity of 13 ohm cm, from Irvin's data (Ref. 7)

 $N_2 = 1.6 \times 10^{17} \text{ atoms/cm}^3$, corresponding to a resistivity of 0.2 ohm cm, from Irvin's data (Ref. 7)

$$d_0 = 0.3\mu$$
,

$$w = 25.9u$$

$$D_{B} = 2 \times 10^{-12} \text{ cm}^{2}/\text{sec}$$

and

$$t = 1.836 \times 10^5 \text{ sec},$$

and are used in the calculation of a, b, c, and d as given by Eq's. (2-5). Finally, N(x) is calculated from Eq. (1).

The parameters which must be calculated for the solar cell model and which pertain to the minority carriers (electrons) in silicon are the mobility, $\mu(N)$, the lifetime, $\tau(N)$, the diffusion coefficient, D(N), and the diffusion length, L(N). Also, the strength of the drift electrical field, E(N), must be calculated. Since all these parameters are dependent on N they vary with the distance, x, as measured from the junction of the solar cell. The mobility, $\mu(N)$, was obtained as a function of N by fitting the experimental data (Fig. 6 of Ref. 6) to an equation of the form

$$\mu(N) = \mu_0 + \mu_1 \log N + \mu_2 (\log N)^2 + \mu_3 (\log N)^3 \qquad \dots (6)$$

The lifetime, $\tau(N)$, was calculated by generalizing Eq. (3-5) of Ref. 6 into the form,

$$\tau = \tau_1 \left(\frac{N}{10^{15}} \right)^{-m} \qquad \dots \tag{7}$$

where the two new parameters, τ_1 and m, must be determined from the spectral response data. The diffusion coefficient, D(N), is calculated from the mobility, $\mu(N)$, according to

$$D = \frac{\mu kT}{e} . \qquad (8)$$

The diffusion length, L(N), is given by

$$L = D\tau . (9)$$

Finally, the drift electrical field, E(N), is calculated from

$$E = -\frac{kT}{e} \frac{d}{dx} \log N. \qquad ... (10)$$

Table 13 shows some of the output information given by the "N" computer program for the drift-field solar cell, No. 82, with values of the two parameters controlling the lifetime selected to be $\tau_1 = 0.3~\mu sec$ and m = 0.4. The units in which the quantities are tabulated are given in order from left to right as cm²/volt-sec for μ , ev/cm for eE, cm for L, cm for x (D), cm for $\Delta x(DD)$, atoms of boron/cm³ for N(FN), and cm²/sec for D. The symbols appearing in Table 13 are part of the FORTRAN language required in the computer program.

Figure 2 shows graphs of the results of the calculations for the drift-field solar cell, No. 82, and of the measurements obtained with the filter wheel spectrometer. The ordinate gives the relative yield of the short-circuit current per photon while the ordinate gives the wavelength in microns. The data are all normalized to unity at $\lambda = 0.803\mu$. Twelve different combinations of τ_1 and m were tried before choosing the best three combinations shown in Fig. 2: m = 0.2 with $\tau_1 = 0.1$, 0.3, 1, and 3 µsec; m = 0.4 with $\tau_1 = 0.1$, 0.3, 1 and 3 µsec; m = 0.4 and $\tau_1 = 0.6$ with $\tau_1 = 0.1$, 0.3, 1, and 3 µsec. The best fit seems to be m = 0.4 and $\tau_1 = 0.3$ µsec.

5. RELIABILITY PROCEDURES

A search is being made to find the reason for the lack of agreement between the present experimental data and three previous sets of data regarding proton fluences required to reduce relative short circuit currents to different prescribes values for 1-ohm-cm and 10-ohm-cm uniform solar cells at the same proton energies. The first set of data (Ref. 2) was obtained during October 1962 for 1- and 3- Mev protons. The second set of data (Ref. 3) was obtained during December 1963 for 0.1-, 0.2-, 0.3- and 0.5-Mev protons. The third set of data (Ref. 4) was obtained during November 1964 for 0.5-, 1.0-, and 2.7- Mev protons. The fourth or present set of data (Ref. 1) was obtained during September 1965 for 0.221-, 0.470-, 1.04-, and 2.53- Mev protons. The indications are that the present set of data give proton fluences about twice as large as they should be except for the 2.53- Mev data which are in good agreement with the other data.

6. ADEQUACY OF FUNDS

The funds provided by the contract are adequate to last at the present rate of expenditure, until December 15, the termination date of the contract.

7. CHANGE IN PERSONNEL

Participating personnel have been

J. De Pangher
D. L. Crowther
Research Scientist
W. H. Harless
E. A. Lodi
G. D. Jones
G. N. Biren
Staff Scientist
Research Scientist
Senior Scientist
Research Laboratory Analyst
Research Laboratory Analyst

8. FUTURE WORK

The "N + E" computer-program arrangement for dividing the base region into layers is to be completed to enable comparisons to be made between theory (Ref. 8)

and experiment for drift-field cells damaged by low-energy protons. An explanation is being sought for the discrepancies observed in the measured values of the proton fluences.

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Table 1

	Computer	Analysis of I	-V Data Obtai	ned for Solar	Cells. Irradiate	d by 2.53-Mev	Protons (13-0-1	to 13-8-5)
CELL	ш	4	<u> </u>	2	RS(UHMS)	PMAX(MW)	I MAXC 4A)	VAAXC
13-0-1	298.	.600		.869	.936	.989	5,830	.334
13-1-1	5	4.000	. 483	.768	.073	1.822	5.463	.333
13-2-1	0	3.600	. 486	.722	.175	1.645	5,263	.330
<13*3*1	298.	1.900	.479	.638	.266	976.	3.787	. 325
13-4-1	9	8.900	.468	.522	.343	.017	1.495	.318
m 13-5-1	298.	6.500	.459	.443	.438	.232	9.602	.311
E 13-6-1	298.	•	0.4350	2.5086	1.2328	7,0033	23,3518	0.2999
13-7-1	298.	0.450	.445	.479	. 735	.107	3.64B	. 300
13-8-1	298.	1.300	~	.658	. 295	.380	4.878	.296
13-0-51	O	1.900	.544	.586	8.545	0,486	5.185	.400
13-1-2	0	1.400	.540	.138	.405	0.375	6,324	394
13-2-2	298.	1.200		.513	7:057	, 305	6.451	.389
13-3-2	0	9.200	.519	.399	7.346	9.484	5.035	.378
13-4-	6	6.200	. 492	.152	6.951	,352	3,345	.357
-5-	9	3.800	.475	.718	6.905	.424	1.678	. 342
13-6-	0	000.7	.431	.228	5.008	.214	7.451	.298
13"7"	3	7.300	.433	.359	.807	.515	7.942	.307
*	0	y • 100	1144	. 404	666.9	.625	A.071	.311
1	6	8 • 600	.561	.277	1.155	,554	1,534	.446
	298.	9.130	.552	.312	.325	.188	1.073	.442
•	0	1.700	.537	.187	1.382	.753	0.881	.434
13.	0	5.500	.513	.920	1 - 275	.296	9.264	.415
13-4-4	O.	2.200	. 485	.746	1.211	.202	6,314	.391
13-5-4	.862	9.530	.471	.525	0.440	. 912	4.100	.375
13.	9	2.100	C 7 7 .	.756	.563	.505	7,191	. 349
13-7-4	9	2.500	C 7 7 .	.309	2.255	644.	6.933	.350
13-8-4	290.	5.100	.445	. 465	1.570	0.541	699.6	.355
•	0	2.800	. 578	669.	. 368	A.703	1.664	.449
•	0	1.700	.574	.039	2.794	8.223	0,532	677.
13-2-5		0.400	• 566	.981	2.951	7.850	6.639	• 446
•	0	7 • 000	. 550	.604	. 934	066.	7.059	.431
•		1.70	155.	.993	.552	3,552	3,115	.409
13-		8.000	.514	.027	2.476	1.391	0.024	.399
13-6-5	On l	3.10	.481	.343	.501	.447	2.401	.370
13-7-5	298.	9.0	. 480	.020	5.440	. 192	3.424	696.
13-8-5		1 • 30		• 433	2.436	060.	4.731	.367

2.53-Mev Protons (13-0-6 to 13-8-9)

Irradiated by

Cells,

Solar

for

of

< 4AXC</pre>
0.4814
0.4730
0.4543 0.3272 0.3372 0.4214 0.4179 0.4168 0.3967 0.3722 0.4096 0.3958 0.4480 0.4262 0.4059 0.3891 0.3743 0.2979 0.3142 0.3734 0.4264 0.4111 0.3937 0.4291 0.3886 0.368 0.439 0.3694 0.378 0.445 144x(4A) 53.5641 50.6853 37.4785 49,9385 61.3544 44.6504 38.7473 31.4459 33,1528 44.6754 37.4946 33,0430 29.5707 27,5255 22,7337 22,5624 58,6232 41.9973 49,0039 45.6169 30.8956 62.4154 59,4416 56.5144 42.3105 39.8422 23,7031 50.0432 30,5804 41.5441 34.9411 35.2291 55,9511 19.3751 PMAX(M±) 25.7992 12.2253 12.8810 27.7791 (.664. 24.0225 22,7763 17,7485 6.1509 6.9423 5,7463 1.4463 11.6154 8.4034 6.6502 3.4145 11,7051 8.7265 12.1507 25.5049 23,3717 19.8123 2,6377 5.3594 0.7501 8.4240 4.9954 3,0034 26.9681 5.5123 1201 20.437 9.703 6.901 18CUHMS) -0.2524 -0.3778 0.1713 0.1955 .1994 .1187 -0.2716 -0.5054 -3.2776 -0.4025 -0.3509 -0.1813 -0.2943 0.3366 3.2445 0.2113 0.3705 -0.1632 -0.4059 -3.3313 -0.5675 0.2715 0.5053 0.5123 0.5565 -0.5429 0.8018 -0.1752 0.3581 -1.5451 .3401 -0.085 1.5069 2.2479 1.9564 1.3422 1.2624 .8084 2.0466 1.9520 .7080 .5988 .5407 .4039 1.4981 .2489 .2522 .6301 .4361 1.3683 2.2987 2.2880 2.1746 2.2039 1.2028 1.7464 .7443 .8596 1.3669 .3692 2.3815 2.3710 .55A6 ,313 .4660 0164. 0.4750 .5220 .5030 .4750 .4520 .5300 0.5770 0.5660 0.5030 0574.0 0.5480 0.5240 0.5110 0.4790 0.4730 0.4830 0.5540 0.5410 0.5150 .4960 0.4810 0644.0 0.4475 0.5410 0.5340 0.5250 0.5160 0.4750 4720 .4450 I-V Data Obtained C 3.C.4A) 49.9000 33.8000 31.5000 27.3000 54.1000 34.7000 37.1000 63.1000 64.3000 61.6000 54.6000 49.0000 46.4990 39.5000 39.5500 42.2000 45.5000 42.7000 37.7000 25.7000 25 - 8500 66.3000 63.5000 60.7000 54.3000 3.6300 0006.0 3.9000 6.1000 50.1000 2.8000 34.2000 39.0000 41.6000 45.7000 Computer Analysis .867 298. 298. 298. 298. .962 .867 .867 298. 298. .862 .862 29B. 298. 298. 799 867 602 29B. 867 298 S & S 962 862 29B 867 298 298 298 967 862 .LL 3-0-6 3-0-9 3-1-6 3-5-6 3-8-6 3-2-7 3-3-7 3-4-7 3-7-7 3-0-8 3-1-8 3-1-6 9-R-8 3-3-8 3-6-8 13-7-8 3-8-8 3-3-6 3-4-9 3-5-9 3-6-9 3-3-6 3-2-8 3-4-8 3-5-8 3-2-6 3-2-6 3-4-6 3-6-6 3-7-6 3-1-6 3-5-7 3-6-7 3-8-7 3-7-9 H-JO opm cw 85 H-JJO mdo I-H

Table 3

Computer Analysis of I-V Data Obtained for Solar Cells, Irradiated by 1.04-Mev Protons (15-0-1 to 15-8-3)

V 4 A X (<)	.350	.353	.350	.339	.327	. 288	. 294	196.	.415	.405	.403	.383	.363	.340	.305	.312	.313	. 448	.432	.423	.401	.380	.360	. 332	.336	.349
I MAXC 4A) 39.4195	9.124	0.553	0.237	7.090	3.625	769.6	8.042	0.268	7.224	4.389	A.312	6.129	9.714	4.259	9,952	9.247	0.215	4.455	3,990	5,989	3.484	7.594	2.975	A . 650	4.309	A.105
PMAX(M4)	3.717	4.344	4.097	2.581	1.018	8.562	.269	.998	9.671	8.828	9.485	7.700	4.453	.667	9.148	.817	470	9.914	9.014	9.473	9446	4.336	1.897	9.518	.861	. 828
RS(UHMS) 0.0890	030	.136	.028	860.	.052	.531	.241	0.392	0.379	0.567	0.468	0.506	116.0	.630	0.021	0.533	537	0.867	0.865	0.516	0.824	686.0	0.921	0.716	1.974	2.711
85	346	286	382	377	.500	.680	.743	.590	. 427	.471	, 330	.387	.482	.234	. 841	.188	.244	.874	.752	.313	.393	.418	.321	.181	.102	3.4787
VAC(V)	.435	.440	.434	. 426	. 416	.390	.391	. 394	.528	.510	.506	.481	. 452	.433	.401	.405	.407	.559	,538	.527	767.	.470	.451	. 423	.426	. 430
15CCMA) 43.1000	3.00	4 • 40	4.30	1.00	7 • 60	0 7 . 4	2.40	4 • 60	4.00	3.20	5.10	3.00	00.9	9.70	4 • 60	3.10	5.50	1.20	09.0	2.10	9.60	3 • 30	3.00	3.20	1.70	4.00
2 E & P & P	0	Ο.	0	9	9	O.	0	0	0	0	O.	O.	0	0	0	9	0	6	Э	O.	9	9	O	0	0	0
CELL 15-0-1	•	-	15	ŧ	15-	10-6-	5-7-	5-8-	0-	5-1-	5-2-	15-3-	15-4-	-2	15-6-	- / -		-0-	-	-5		15-4-	-5-	15-6-	- 1 -	10-8-3

Table 4

Computer Analysis of I-V Data Obtained for Solar Cells, Irradiated by 1.04-Mev Protons (15-0-4 to 15-8-6)

76 H=106 15-10-16-16-16-16-16-16-16-16-16-16-16-16-16-	52.3900 51.5000 53.0000 50.3000 44.1000	0.5110	V 66	5.513	7 444		200
15 - 1 - 2 - 2 - 2 - 2 - 2 - 2 - 2 - 2 - 2	1.00 0.00 0.00 0.00 0.00 0.00				****	(())	ナイヤ・
15 1 1 2 1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	0.00		.047	3,763	6.857	3,433	.388
15 - 5 - 4 - 2 - 2 - 2 - 2 - 2 - 2 - 2 - 2 - 2	0.00	499	.006	0.789	484	4.855	. 389
15-6-4 15-6-4 15-6-4 15-6-4 15-6-4 15-6-4 15-6-4 15-6-5 15-6 15-6	4.10	.479	.914	0.318	6.080	2,523	.377
15-5-4 15-6-4 15-7-4 15-16-15 15-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16-16 16-16 16-16-16 16-	00.6	.461	.747	0,915	3.549	7.433	.361
15-6-4 15-8-1 15-8-4 15-8-4 15-8-4 15-8-5 15-8-5 15-8-5 15-8-5 15-8-5 15-8-5 15-8-5 15-8-5 15-8-5 15-8-5 15-8-6 15-8-8-6 15-8-8		.445	.708	3,962	1.470	2,962	.348
15-8-4 15-8-4 15-1-5 15-1-5 15-2-5 15-8-8-5 15-8-8	4.00	.420	.117	0.303	9.414	9.204	. 322
15-8-4 15-10-5 15-11-5 15-2-5 15-4-5 15-4-5 15-6 15-6	2.40	. 422	.880	1.464	.883	6.985	. 329
15-0-5 15-1-5 15-2-5 15-2-5 15-3-5 15-4-5 15-6-5 15-6-5 15-6-5 15-7-7	4.70	. 426	934	1.308	9.508	8.793	.330
101101101101101101101101101101101101101	2.30	. 592	3.1077	-1.2188	17.4464	34,5751	0.4757
15-2-5 15-3-5 15-4-5 15-6-5 15-6-5 15-6-5 15-6-5	1 - 40	.583	.882	1.136	7.035	5.172	.471
15-8-5 15-8-5 15-8-5 15-6-5 15-6-5 15-6-5	2.50	.582	.841	1.049	7.497	7.257	.469
15-6-5 15-5-5 15-6-5 15-6-5 15-6-5	0.50	.562	.253	1.510	5.806	4.801	.454
15-5-5 15-6-5 15-7-7-29	5 • 4 U	.541	.618	1.005	3.798	1.808	.433
5±6±5 247±7	3.00	.524	.457	944	2.129	8,916	.419
5-7-5	3.	. 493	, 334	1.052	9.729	4.679	.394
` '	0./	.497	.301	0.334	.359	3.653	. 395
5-8-5	8.70	164.	.327	0.831	9.384	5.085	.394
5-0-6	2. 03	. 585	.955	0.174	6.742	6.190	.475
5-1-6 29	0.40	.567	.770	•006	5.128	4.935	.457
2-5-6 49	1.00	.555	.721	.)33	5.002	5,563	.450
5-3-6 29	4.53	.533	.547	.125	1.273	9. 484	.426
5-4-6	5.8 0	.505	.522	.088	6.971	1.743	.405
15-5-6 29	0 * 30	064.	.505	070.	4.460	6.573	394
62 9-9-	4 . 30	.450	.542	.042	1.426	0.984	.358
67 9-1-	2.35	.461	.587	0.178	.010	9.542	.371
67 9-4-	5 - 23	.456	987	.293	1.536	1.207	946

Table

Irradiated by 1.04-Mev Protons (15-0-7 to 15-8-9)

V4AX(V). 0.4430 0.4247 0.4143 0.3539 0.3324 0.366R 0.3244 0.4170 0.4170 0.3387 0.3375 0.3873 .3337 IMAX(4A) 60.7333 59.5692 61.7423 56.7589 34,2402 32,1492 34,2627 58.9233 58.6732 55.1549 31.4358 33.3477 59.8748 47.9039 45,6535 34,0088 31.1294 29.5420 62,3325 63,3418 54.5265 50,1558 42.0260 34.8437 40.9271 PMAX(M4) 26.9043 25.2973 24.1445 11,2379 10,1984 21,9839 17,5715 14,4843 11,0597 10.5425 20,7226 16,3895 13.1909 10.0054 9.5545 26.0013 25,5811 25.9903 11.5837 22.7491 18.4437 11.1291 5.005 (SCUHMS) 0.1515 0.3262 0.4975 0.3792 . 5273 .2986 .4456 .7456 .5589 . 6565 .5291 0,3855 0,3225 0,1649 0.6085 0.6663 0.4330 9.6494 0.5897 0.5785 0.6347 0.5383 0.0961 . 43A2 Computer Analysis of I-V Data Obtained for Solar Cells, 1.5163 1.5179 .4993 .3809 .5317 .609B 4295 .4502 .6111 ,7351 4975 . 4381 .4812 .6319 .4415 1.7907 .3820 .4455 .3757 .3696 6826 .5193 8456 ,5526 .5448 .5017 .4270 0.5490 0.5370 0.5290 0005. .4740 .4550 .4270 .4340 VUCCV) 0.5540 0.5400 0.5400 . 4230 .4570 .4300 .5000 0.5390 0.4730 .4650 .4390 .4330 0.5400 0.5100 0.4810 .4420 00 **つ** 0 66.6000 67.7000 000 .8000 50.6000 53.2000 5.6000 38.8000 66.1000 65.0000 0006.49 61.9000 42.4300 35.2000 33.5500 0004-49 (A #) 2 S 36.7000 39.3000 36.0300 0006.69 68.3000 69.7000 55.4330 34.0000 37.4000 45.7 -EMP 298. 298 296 298 298. 298. 298 298. 298 298 238. 298 298. 298 867 298. 867 298 867 298 863 298 862 15-0-7 15-1-7 5-2-7 5-4-7 5-1-8 -1-9 5-8-7 5-3-8 5-4-8 5-0-8 5-2-8 5-5-8 5-6-8 15-7-8 15-8-81 6-0-5 5-5-6 5-3-9 5-4-5 5-5-5 15-6-9 15-7-9 9-X-S H-J opm cm KCV JO OPW CW H-JO OJIN CM

_ວ	Computer Analys:	sis of I-V Data	Obtained for	Solar Cells,	Irradiated by	1.04-Mev Protons	(16-0-1 to 16-	-8-5)
1000 1000 1000 1000 1000 1000 1000 100	년 보 연 구 교	女子 しょうり	>0	2	LSCUHMS)	A X C M	MAXC ACC	X A X
,			V C C :	101.	0 4 5 4 0	ال (ر ال	3.26.0	707.
9	9	0.4.0	675.	.080	0.244	4.665	2,510	.468
	9	5.400	.568	985	0.210	3.180	0.349	.460
-	O	0.66.0	.548	869	0.239	0.586	5.085	.446
(16-4-1	0	4.200	,524	.660	0.051	7.042	0.180	. 424
2 16-5-1	0	9.930	.508	.535	.022	4.991	6.432	. 411
m 16-4-1	0	.270	.478	.516	.054	1,511	0.198	.384
I 10-7-1	.862	2.050	475	508	.036	1.164	9,115	.383
,,	298.	4.700	. 483	840	0.284	966.	0,991	.386
16-0-2	9	6.370	.586	358	. 437	.413	1,255	.470
_	.982	5.300	.581	.347	0.302	.572	0.191	.462
2	0	4.720	.578	,338	0.310	8.221	9,668	.459
-	.862	2.730	.566	.179	0.285	7,256	8,125	.452
16-4-	0	8.750	.548	.073	0.285	5.188	4.538	.438
16-5-	0	5.550	.532	.862	0.115	3.677	2.082	.426
16-6-	9	9 • 400	.503	.858	0.253	0.599	6.330	.402
I 10.7.2	0	8.750	.500	.854	0.541	0.463	5.813	.405
16-8-	9	0.700	.504	06	0.256	1,035	7.444	.402
16-0-4	0	9.520	.557	396	.218	9.000	4.250	.451
16-1-4	.862	9.920	.543	0.8	.428	7,663	3.666	.434
	0	6.430	.535	05	.463	5.400	1.205	. 421
16-3-4	0	61.1700	.510	12	.453	.498	6.131	004.
-	9	1.580	. 434	6	.375	7.961	6.954	.380
~	9	4.370	.467	25	.315	4.784	0.221	198.
16	0	9.640	. 444	17	.734	0.736	2.295	.332
-	.86≲	0.150	.439	74	.417	0.823	2.140	.336
16 - 8 - 4	298•	9.300	. 443	4 3	, 453	1.574	4,715	.336
•	0	1.530	. 544		370.	7.458	4.102	. 428
-	298.	1.200	. 534	25	.322	6.377	3.964	.412
16-2-5	* P67	?	.523	83	.331	4.775	1.807	.400
16-3-	.862	00	.500	11	.424	1.972	7.879	.379
0 16-4-5	298.	000	. 471	∞	.447	7.909	9.930	.358
16-5-	.98.	.920	.453	69	.339	4.697	2,438	.346
주 16 6 5 7	.862	5.0	•	1.7055	614.	1.03	34.7055	
15	. 96 >	33.9300	.421	32	.202	. 369	4.147	.321
15-8-5	.862	42.0000	496	66	120	.533	5,132	.320

	O	Computer Analys	is of I-V	Data Obtained f	or Solar Cells,	. Irradiated by	y 470-kev Protons	(14-0-1 to 14-	8-4)
<u>ا</u>	ו ור	<u>E</u> .	ISC (AM	30(4)	Z	(OHAS)	PMAXCM	MAKCAD	J X V Y
7	1-0-	Q,	6.930	.516	.865	€2C•	0.754	7.66°C	.407
14	-1-1	Ŋ	6.730	.518	.767	.032	1.069	1,085	.412
1 4	-2-1	9	0/4.9	.512	,652	.133	0.721	1.042	.406
+	-3-1		5.900	404.	600	49	616.6	0.594	. 394
Ţ	1-7-	⊅	1.340	.466	.778	157	7.015	5,413	.371
9-	-5-1	⊅	7.030	. 441	. 008	.491	4.571	1,315	.352
H	-6-1	298.	49.3000	0.3974	2.8027	-1.1837	10,3515	33.4150	
14	-7-1	O	3.100	.400	. 484	.739	9.817	1.942	. 307
7	8-1	0	0.600	. 407	.759	392	.611	3,733	.314
7 1	-0-5	9	3.600	.548	666.	. 695	9.769	5.945	.430
14	•	0	1.930	.533	.529	065.	9.095	5.299	. 421
14	-2-2	Š	0.930	.512	.475	.400	.736	4.219	.401
14.	-3-5	9	000.7	474.	.435	.597	5.187	0.619	.373
71 9	•	0	9.530	. 441	.987	.055	1.151	5.809	.339
7	ŧ	9	4.450	.413	.657	.149	.854	7.621	.320
7 [•	O,	6.530	. 364	.467	.207	.359	9.757	.271
14	2-1-	9	6.500	.363	.241	.341	435	9,916	.272
- 1		O	1.000	370	000	.770	.249	3.278	.268
7	•	9	5.650	.543	.901	.225	4.966	8.696	. 425
14	-1-3	6	4 • 4 5 0	.544	046.	.236	4.147	7,420	.420
CM CM	•	O	4.420	.531	.747	• 458	3,303	7,589	404.
T T	*3*3	6	3.890	.502	.620	.572	1.471	966.9	.376
ųo	•	9	9.070	.468	.779	.483	7.985	1.741	.347
4.	-5-3	6	5.450	. 438	.142	.186	5.345	7.230	. 324
- [-	E = 9 =	6	2.470	.385	.505	.181	.525	5.229	.272
H	-7-3	0	0.00.0	.390	. 526	. 023	1.393	0.587	.280
4	-8-3	0	2.400	.398	479	190	2,063	2,559	.283
	7-0-	6	2.750	. 560	.313	.214	4.670	5.522	. 444
14	-1-4	O	1.550	. 557	.434	. 363	4.088	4.239	. 444
CE	-2-4	O	1.320	.548	.264	.197	3.535	4,230	.434
- w	-3-4	9	1.000	. 527	.151	194	1.061	0.471	.417
ųo ųo	カーカー	9	9 • 350	.503	.300	.386	7.334	3,635	.397
- T	-5-4		3.400	.486	676.	40	4.986	9.575	.388
-!: -!:	7-9-	Ò	• 230	. 451	.137	.545	439	5.422	.357
7	オートー	9	1.20	. 451	.877	2	6.35	4.065	. 358
3	18 - 4		0 • 300	• 458	900€	. 463	.504	5.467	.359

Computer Analysis of I-V Data Obtained for Solar Cells,

Irradiated by 470-kev Protons (14-0-5 to 14-8-7)

0.3537 00.00 00 0.3722 0.3997 0.378 783 593 1 MAX(MA) 51.8783 51.5597 51.7637 49.3023 39.5555 27.7850 24.7274 24.5900 39.2502 35.5629 31.1554 28.5375 24.2313 21.5699 37.6720 43.8943 38,4011 38.4363 34.6588 34,4321 32,9152 27.5634 24.0130 PMAX(MN) 24.8929 24.1757 23.3907 20.9865 9.3284 8.5493 8.0587 18.2121 17.7493 17.5480 15.3890 15,8123 13,1526 11,7780 9.3210 8.4254 8.8020 17.8185 6.7420 17.5413 1.4847 9.7083 6444.9 4SCUHMS) -0.3460 -0.0914 0.0467 -0.1701 -0.4729 -0.9416 -0.2561 0.4549 0.0342 -0.0476 -0.0416 -0.1898 -0.0844 -0.4468 -0.3479 -0.5998 -0.4353 -0.5794 0,3335 3.3446 -0.0705 1.6580 1.7028 2.5407 2.4788 2.3007 2.3049 2.1102 1.9792 2.0255 1.9236 1.2007 .1956 .1980 1.8146 ,2538 .4548 .3067 1.7140 1.8187 1,5827 2,9489 .2011 .4474 .4510 0.5000 0.5900 0.5900 0.5645 0.4645 0.4440 0.4440 0.4505 15c(44) 57.4500 56.9200 57.1300 25.7300 40.2200 39.1500 32.0300 3.6700 43.2700 49.0000 31.0800 27.8000 30.2000 44.5200 43.5000 0080.04 35.0300 24.3300 38.9700 9.0500 54.4200 35,3800 0056.65 0066.65 2983 2983 298. 298. 298. 298. 298. 498. 298. 298 298 298 298. 298. .962 .867 298. 29B. 298. 698 296, 298 867 4-5-6 1-9-4 1-1-1 (425) E-E IT TI h-l (12µ) EST-88

•	- deministration							
こだし	W	ダドンつの	100	7	MH(!)	AXCM	AAXC	MAXC
10-0-1	Ç	5.20 0	.532	.041	1.278	9.263	4.470	378
10-1-1	0	1.690	. 527	.346	.755	.965	3.794	.376
~	9	0.500	.520	.196	.586	402	2.726	.369
10	6	1.000	~	.636	8	.516	0.461	.363
30-4-1	.862	23.3000	₹•	4.1750	•	6.2881	17,9844	
0	0	000.9	0	.759	.517	.754	2.240	.306
10-7-1	6	006 * *	.433	.579	0.482	.481	1.482	.303
ar.	0	2.900	9	,723	040	.661	2,089	.302
0	6	9.400	. 396	.970	.920	.956	2.420	.265
	Ò	3.800	.393	.6H4	.358	.801	7,188	.261
-2-	9	7.500	.389	.184	.371	.314	0.532	.258
10-3-	9	0000+	.380	904	.692	.760	9,413	. 258
14	9	0.500	.363	.468	.648	198	5.635	. 242
10-6-	9	3.400	.318	.001	.511	.174	9.962	.218
10-7-	Ò	2.500	.314	.672	447	.012	415	.213
8	Q,	.400	.320	670.	.402	.130	0.242	.208
0	6	9.300	.551	.874	.138	.803	4.543	. 444
	6	9.200	.543	.493	.188	.807	5.17.	.438
10-2-3		0009.67	0.5210	.739	115	.900	.895	. 421
10-3-	0	9.000 ·	.500	.848	.261	.740	3,971	.403
- 7 -	0	8.900	.468	20	• 05¢	.980	3,419	.368
	0	8 - 700	.396	1.3	.226	.558	2.221	.297
•	9	4.850	.399	20	.072	.547	8.292	.301
	0	6.400	407	22	260.	101.	6.697	.304
10-0-4	9	000	.512	516	.020	. 223	9.035	.415
•		3.000	.508	536	.063	.016	9.027	.410
10-2-4	0	3.000	. 498	86	.105	.571	9.845	.400
-	294.	• 700	.485	04	.116	.207	9.630	. 393
7-7-01	9	2 • 300	. 458	10	.150	.806	7.914	.365
10-6-4	9	008.	. 393	47	•013	.758	4.055	. 298
•	Š	8.500	. 394	6	.113	.012	3.219	.301
10-8-4	298.	000.0	.403	£.	.213	.511	4.535	6

Table 10

(A D X C V) 0.4472 .3869 .4359 .3069 1.2895 .3053 4224 .4148 . 2949 .4320 0.3237 0.4313 0.4226 0.4102 0.3841 0.3609 .4186 .4003 .3871 0.3480 .306 0.291 0 00 Irradiated by 221-kev Protons (10-0-5 to 10-8-9) 44.6979 30.9298 43.7952 44.9508 45.4228 38,5423 42.2029 28,9788 44.6155 39,9169 59.2624 44.9894 39,4727 31.6738 59,3369 58.7725 54.8084 44.0450 54,5928 3,1890 60.4211 45.3211 61,8611 56.0916 41.4931 62.246 60,975 19.1854 17.9963 8.8752 9.3920 17.2712 20,1199 12.0250 6,3295 4.2466 9,6710 8.4824 11.2809 24,3909 11,7731 26.6610 25.8664 25,3884 21.9384 14.2590 26.3023 13.6075 5.0139 27.1457 25,3784 23.4187 20,3907 5.9654 ASCUHMS) 0.0396 0.1048 0.3678 0.2709 0.1600 0.1856 0.2734 0.2848 0.1867 0.2931 0.0487 0.0469 0.0573 0.1755 -0.2965 0.2739 0.4581 0.2233 -0.2340 -0.4959 -0.6873 -0.7880 -0.8579 -0.0427 0.431 Computer Analysis of I-V Data Obtained for Solar Cells, 2.4652 1.6423 1.5650 1.5383 2.0396 3.1546 2,5116 .8503 2,1634 1.5825 1,6196 2.1760 1,8838 1,8858 .7306 9860 .5927 1.5582 1.9641 1.9151 1,9533 1.6756 3.0562 1.5665 5448 .5119 2,0287 .8496 • 0.5200 0.4640 0.4060 0.5280 0.5220 0.5150 0.5520 0.5485 0.5060 0.4370 0.5290 .4685 .4040 0.5530 0.5430 0.5570 0.5300 .4260 0.4280 0.5010 0.5220 .3980 0 49.7000 43.8000 44.2000 37.3000 34.7000 37.5000 50.4000 49.5500 50.0500 49.3000 49.8500 49.6500 45.4500 47.3000 67.2000 65.0000 65.6500 64.4000 61.4000 54.0000 50.4500 53.8000 69.2000 68.3000 68.1000 66.7000 49.3000 46.7000 0009-19 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298. 298 298. 298. .962 298 298 298 298, 298 298, 298 298 93 0-6-5 0-3-6 9-9-01 0-2-6 9-8-0 0-1-0 10-2-1 10-0-5 0-1-5 0-2-5 0-3-5 0-4-5 0-8-5 9-0-0 9-1-0 9-1-0 0-3-7 1-9-0 6-0-0 0-1-0 6-2-0 0-3-6 6-7-0 0-4-0 0-4-0 9-8-1-0-0 1-4-0 10-7-7 0-8-7 H-J ohm cm 29 179 60T-H

Table 11

V4AX(V) 0.4595 0.4516 0.4128 0.4431 .4034 .3505 .3345 .4528 .4334 .3426 .4316 .4318 .4274 .3956 .3299 .2890 .3323 .4594 .4490 Irradiated by 221-kev Protons (17-0-1 to 17-8-4)IMAX(MA) 55.8072 54.8234 52.8716 29.7955 27.7032 32.2420 39.7822 39.7822 37.4343 55.2449 53,8339 21,8479 38,4254 23.4559 41.2737 39.9234 40,5517 40.8531 39,8527 34.4842 39,775 34.115 PMAXCMA) 25.6416 24.7606 10.7127 15.1018 8.5577 7.7075 8.0371 7.7463 7.9252 24,4781 23.0820 20,9186 9.8269 9.2680 6.6547 17.5104 7.4587 6.4527 0.5454 0.4787 4.4361 4SCUHMS) -0.2413 0.2141 -0.1755 -0.0853 -1.3148 -1.3803 -1.0808 -0.4403 -0.3303 -0.4303 -0.0459 -0.3137 -0.7398 -0.9534 -1.3149 1690.0-0.4422 0.2694 -0.0021 0.2467 Computer Analysis of I-V Data Obtained for Solar Cells, 3.1279 2.7716 2.2158 2,1938 1.2184 2,4729 2.0010 1.9069 2,0068 1.2237 2,1992 2,1754 1.1931 1.5341 0.4520 0.5278 0.5818 0.5769 0.5685 0.5482 0.4265 .4330 0.4517 3.5052 0.4642 0.5193 0.5735 0.5620 0.5402 0.5030 0.4290 0.5242 3.3892 0.3900 .3950 3.3000 52.1200 62.1500 59.9800 59.5830 35.2800 33.3000 37.6030 0065.9 45.5000 45.5200 43.5600 43.0500 28.6500 25.5000 27.3000 0011.44 43.5500 43.8500 42.9600 44.2300 43.5500 2.2000 298. 298. 298. 298. 298. 298. 298. 298. 298. .967 298. 298. 298. 298. 298. 298. 298. .967 298. 298. TI 3-1 (25µ) 17-0-2 1-1-4 -2-4 CELL 17-0-1 7-9-1-1-4 7-8-7 7-0-1 7-7-1 17-7-1 17-8-1 80 TI 4-3 (124) EZZ-JC

Table 12

Computer Analysis of I-V Data Obtained for Solar Cells, Irradiated by 221-kev Protons (17-0-5 to 17-8-6)

VMAXCO . 4 MMC	. 42	.419	.40	.354	.282	.286	.289	. 428	. 421	. 41	.394	.349	.28	.284	. 23
IMAX(4A)	1.142	2.314	1.480	2.211	4.261	4.903	5.224	3.044	1.575	2.415	1.983	7.664	A.951	006.0	5.934
P44 X (M#) 27.0805	6.26	6.14	4.54	2.04	5.48	5.43	5.95	6.98	5.96	5.82	4.43	1.90	6.57	5.61	90.9
45(3HMS) -0.2672	0.254	.048	.176	.503	.576	.514	0.508	0.312	.290	. 188	.196	.420	. 555	.558	.547
∑ • 24 C)	39	. O.	A.A.	. 79	06.	96	90	.62	.68	. 46	111	.01	.01	.95	2.0633
V3C(V) 0.5475	.543	.538	.518	.481	.405	. 405	.412	. 545	.541	.535	.520	.478	.405	.405	.411
15-(44)	09.6	0.3	9.1	1.1	1.6	4.3		~• 5	1.2	71.8500	0.6	7 • 7	1.2	~	Z • 5
- 268 208 • 3	9	0	0	0	O	0	0	0	6	0	6	9	0	0	O.
6 CELL 17-0-5	17-1-	17-2-	17-3-	17-4-	17-6-	17-7-	17-8-	17-0-	17-1-	2	17-3-	17-4-	17-6-	17-7-	1/-8-

Table 13

Output of t	Output of the "N" Computer Program	Program for Drift	for Drift-Field Solar Cell	No.82, for Values of the	Parameters,
		$\tau_1 = 0.3$	3 usec and m = 0.		
MOBILITY	ELECT FIELD	DIFF LENGTH	DIST FR JUNC!	THICKNESS IMP CONC	DIFF COEFF
(MA)	m	(T)	(D)	(DD) (FN)	(<u>a</u>)
319.543	0.863	0.3046E-02	0.1063E-03	0.1063E-03 0.1224E 16	34.1102
18.0	-31.0131	0.2934E-02	2E-0	.2399E-03 0.1334E 1	34.0704
310,721	3.013	0-4	2E-	30.177	33,8822
296.240	0.276	36-0	-0	.1480E-03 0.2371E 1	3.507
275.072	4.366	428E-	0.8040E-03	0.3162E 1	2.96
247.752	56.209	268E-0	.9364E-0	.1324E-03 0.4217E I	2.254
214.804	6.416	13E-0	.1068E-0	319E-03 0.5623E 1	1.402
176.759	5.404	C	.1203E-0	.1343E-03.0.7499E 1	0.419
134,149	53,458	.1819E-0	42E-0	E-03.0.1000E 1	29.3178
087.492	0.767	1682E-0	.1488E-0	.1466E-03 0.1334E 1	8.111
037.312	7.453	51E-0	645E-0	.1568E-03 0.1778E 1	6.814
984.147	3.578		1816E-0	-03 0.2371E 1	5.440
28.526	39,155	1308E-0	-	.1900E-03 0.3162E 1	24.0024
70.969	4.144	1196E-0	E-0	E-03 0.4217E 1	
12.002	426	10	E-0	E-03 0.5623E	
52.153	1.736	0	28E-0	423E-03 0.7499E 1	19.4432
91.954	3.330	68E-0	5E-0	1E-03 0.1000E 1	17.8870
884	0.156	0.7971E-03	0.3356E-01	0.3017E-010.1334E 18	16.1274
				-	

LIST OF FIGURES

- Figure 1 Diagram showing the different layers in the construction of a drift-field solar cell.
- Figure 2 Graphs of the measured and calculated spectral responses of the drift-field solar cell, No. 82.

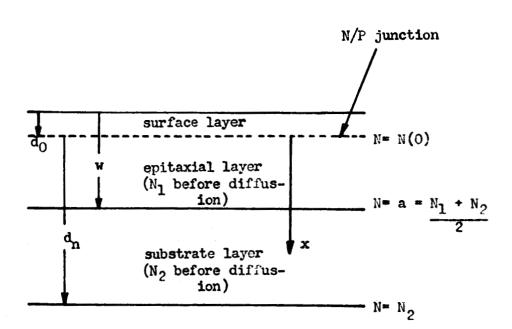


FIGURE 1

RELATIVE YIELD PER PHOTON